

4CH HIGH-CURRENT DARLINGTON SINK DRIVER

The TD62064P/AP/F/AF and TD62074P/AP/F/AF are high-voltage, high-current darlington drivers comprised of four NPN darlington pairs.

All units feature integral clamp diodes for switching inductive loads and all units of TD62074P/AP/F/AF feature uncommitted collectors and emitters for isolated darlington applications.

For proper operation, the substrate (SUB) must be connected to the most negative voltage.

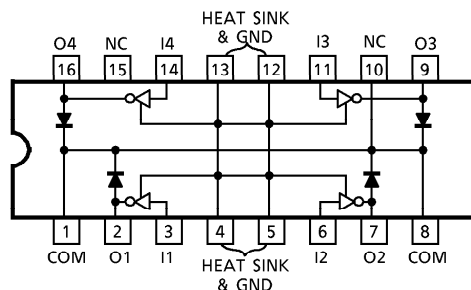
Applications include relay, hammer, lamp and stepping motor drivers.

FEATURES

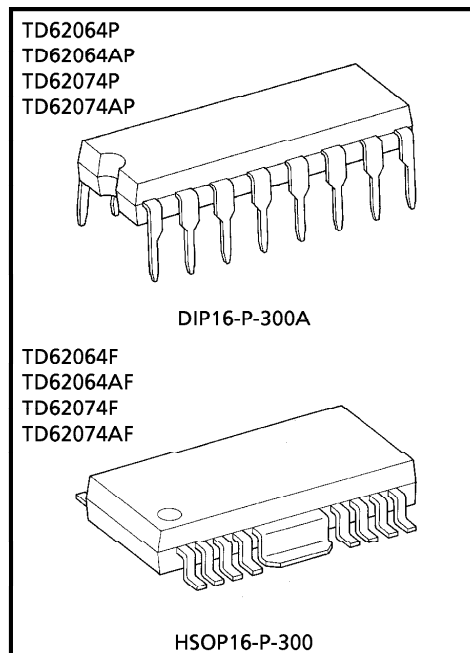
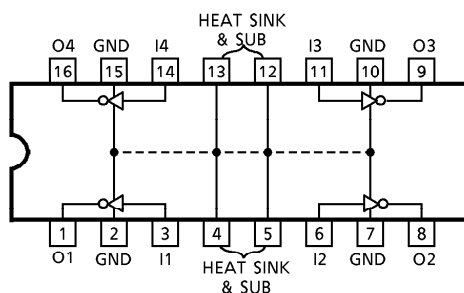
- Output current (single output) 1.5A (Max.)
- High sustaining voltage output
35V (Min.) (TD62064P/F, 074P/F)
50V (Min.) (TD62064AP/AF, 074AP/AF)
- Output clamp diodes : TD62064P/AP/F/AF
- Isolated darlington array : TD62074P/AP/F/AF
- Input compatible with TTL and 5V CMOS
- GND and SUB terminal = heat sink
- Package type-P, AP : DIP-16pin
- Package type-F, AF : HSOP-16pin

PIN CONNECTION (TOP VIEW)

TD62064P/AP

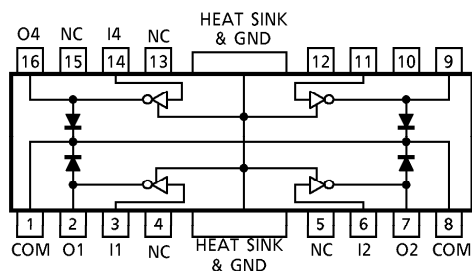


TD62074P/AP

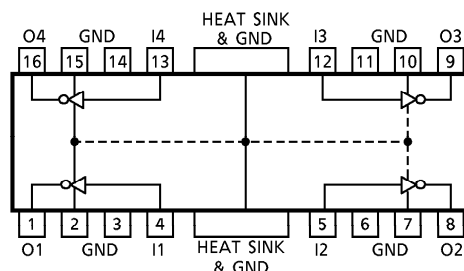


Weight DIP16-P-300A : 1.11g (Typ.)
HSOP16-P-300 : 0.50g (Typ.)

TD62064F / AF

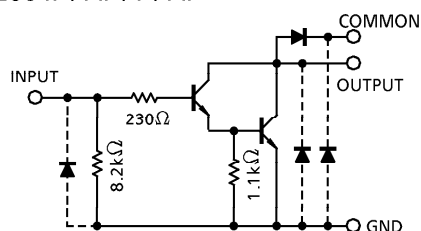


TD62074F / AF

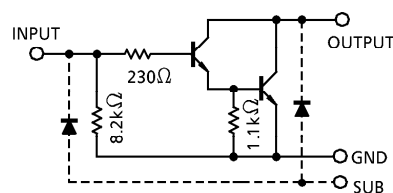


SCHEMATICS (EACH DRIVER)

TD62064P / AP / F / AF



TD62074P / AP / F / AF



(Note) The input and output parasitic diodes cannot be used as clamp diodes.

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Output Sustaining Voltage	P, F	$V_{CE(SUS)}$	- 0.5~35	V
	AP, AF		- 0.5~50	
Output Current		I_{OUT}	1.5	A / ch
Input Current		I_{IN}	50	mA
Input Voltage		V_{IN}	- 0.5~17	V
Clamp Diode Reverse Voltage	P, F	V_R (Note 1)	35	V
	AP, AF		50	
Clamp Diode Forward Current		I_F (Note 1)	1.5	A / ch
Isolated Voltage	P, F	V_{SUB} (Note 2)	35	V
	AP, AF		50	
Power Dissipation	P, AP	P_D	1.47 / 2.7 (Note 3)	W
	F, AF		0.9 / 1.4 (Note 4)	
Operating Temperature		T_{opr}	- 40~85	°C
Storage Temperature		T_{stg}	- 55~150	°C

(Note 1) TD62064P / AP / F / AF

(Note 2) TD62074P / AP / F / AF

(Note 3) On Glass Epoxy (50 × 50 × 1.6mm Cu 50%)

(Note 4) On Glass Epoxy (60 × 30 × 1.6mm Cu 30%)

RECOMMENDED OPERATING CONDITIONS ($T_a = -40 \sim 85^\circ\text{C}$)

CHARACTERISTIC		SYMBOL	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Output Sustaining Voltage	P, F	V _{CE (SUS)}			0	—	35	V
	AP, AF				0	—	50	
Output Current	P, AP (Note 1)	I _{OUT}	DC1 Circuit, Ta = 25°C		0	—	1250	mA / ch
			T _{pw} = 25ms 4 Circuits T _j = 120°C Ta = 85°C	Duty = 10%	0	—	1250	
	Duty = 50%			0	—	390		
	Duty = 10%			0	—	907		
	Duty = 50%			0	—	172		
Input Voltage		V _{IN}			0	—	8	V
	(Output On)	V _{IN (ON)}	I _{OUT} = 1.25A		2.5	—	8	V
	(Output Off)	V _{IN (OFF)}			0	—	0.4	V
Input Current		I _{IN}			0	—	20	mA
Clamp Diode Reverse Voltage	P, F	V _R	TD62064P / AP / F / AF		0	—	35	V
	AP, AF				0	—	50	
Clamp Diode Forward Current		I _F			—	—	1.25	A
Isolation Voltage	P, F	V _{SUB}	TD62074P / AP / F / AF		—	—	35	V
	AP, AF				—	—	50	
Power Dissipation	P, AP	P _D	Ta = 85°C (Note 1)		—	—	1.4	W
	F, AF		Ta = 85°C (Note 2)		—	—	0.7	

(Note 1) On Glass Epoxy ($50 \times 50 \times 1.6\text{mm}$ Cu 50%)

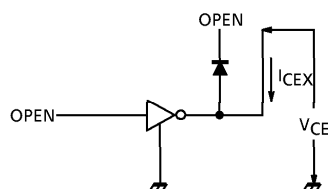
(Note 2) On Glass Epoxy ($60 \times 30 \times 1.6\text{mm}$ Cu 30%)

ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)

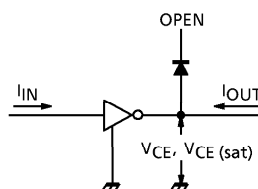
CHARACTERISTIC		SYMBOL	TEST CIRCUIT	TEST CONDITION		MIN.	TYP.	MAX.	UNIT
Output Leakage Current	AP, AF	I _{CEX}	1	V _{CE} = 50V, Ta = 25°C		—	—	50	μA
	V _{CE} = 50V, Ta = 85°C			—	—	500			
	P, F			V _{CE} = 35V, Ta = 25°C		—	—	50	
				V _{CE} = 35V, Ta = 85°C		—	—	500	
Collector-Emitter Saturation Voltage		V _{CE (sat)}	2	I _{OUT} = 1.25A, I _{IN} = 2mA		—	—	1.6	V
				I _{OUT} = 0.75A, I _{IN} = 935μA		—	—	1.25	
DC Current Transfer Ratio		h _{FE}	2	V _{CE} = 2V	I _{OUT} = 1.0A	—	800	—	
					I _{OUT} = 0.25A	—	1500	—	
Input Voltage (Output On)		V _{IN (ON)}	3	I _{OUT} = 1.25A, I _{IN} = 2mA		—	—	2.4	V
Clamp Diode Leakage Current	AP, AF	I _R	4	V _R = 50V, Ta = 25°C		—	—	50	μA
	V _R = 50V, Ta = 85°C			—	—	100			
	F			V _R = 35V, Ta = 25°C		—	—	50	
				V _R = 35V, Ta = 85°C		—	—	100	
Clamp Diode Forward Voltage		V _F	5	I _F = 1.25A		—	—	2	V
Input Capacitance		C _{IN}	6	V _{IN} = 0V, f = 1MHz		—	15	—	pF
Turn-On Delay	P, F	t _{ON}	7	C _L = 15pF	V _{OUT} = 35V R _L = 29Ω	—	0.1	—	μs
	AP, AF				V _{OUT} = 50V R _L = 42Ω				
Turn-Off Delay	P, F	t _{OFF}			V _{OUT} = 35V R _L = 29Ω	—	1.0	—	
	AP, AF				V _{OUT} = 50V R _L = 42Ω				

TEST CIRCUIT

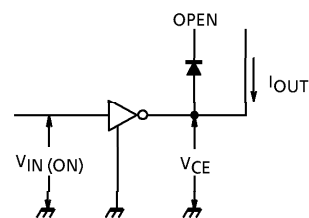
1. I_{CEX}



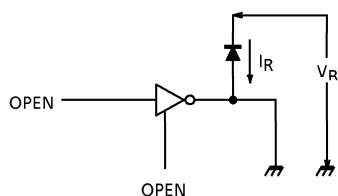
2. $V_{CE(sat)}$, h_{FE}



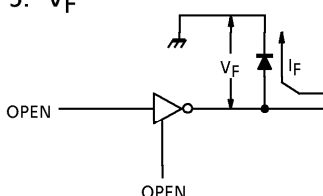
3. $V_{IN(ON)}$



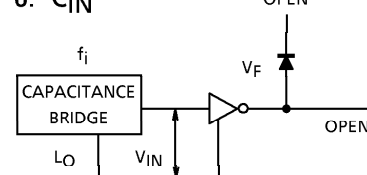
4. I_R



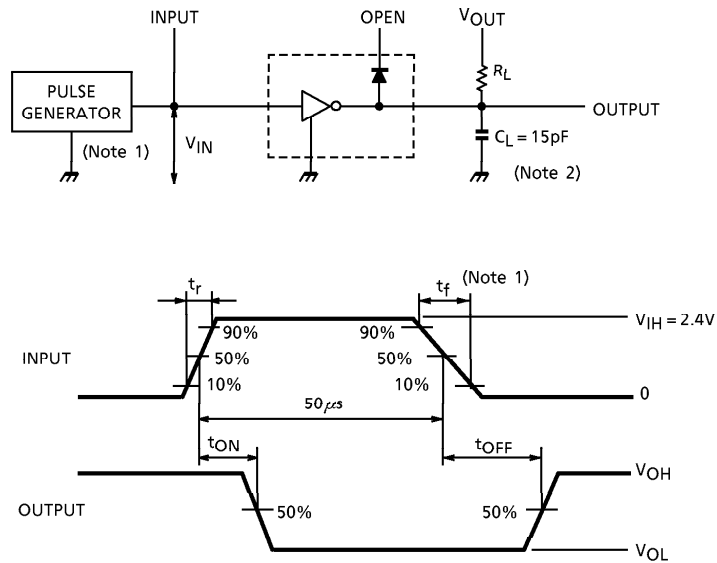
5. V_F



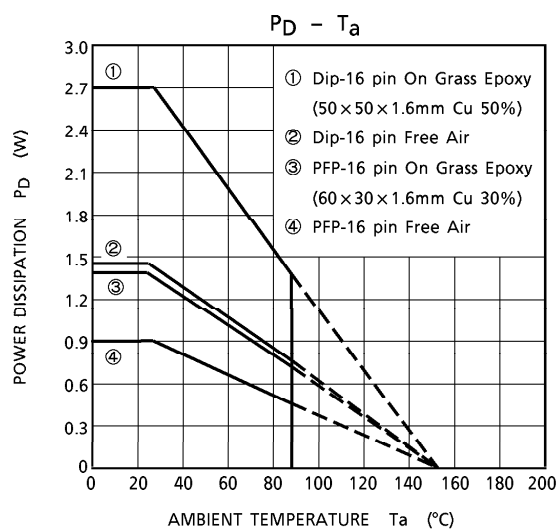
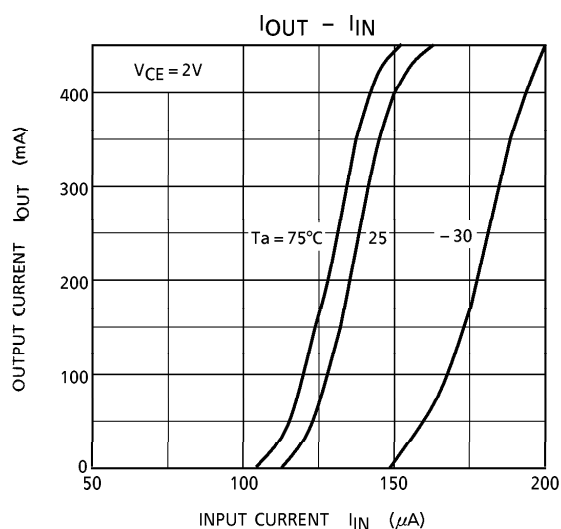
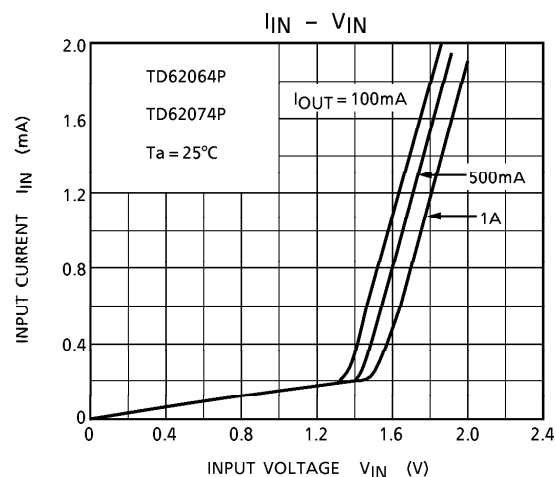
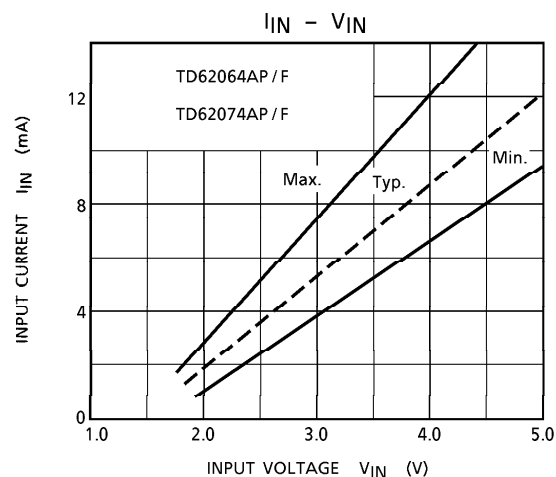
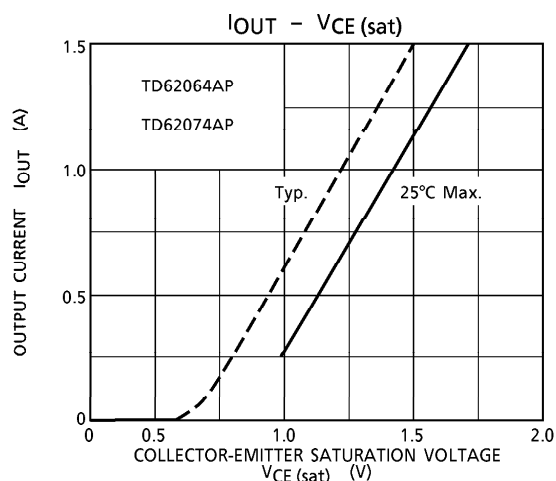
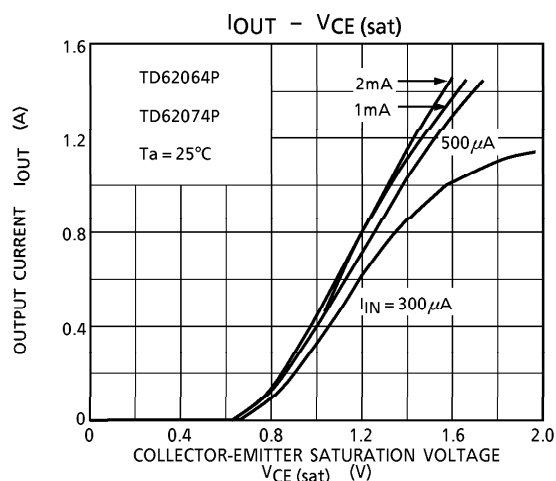
6. C_{IN}

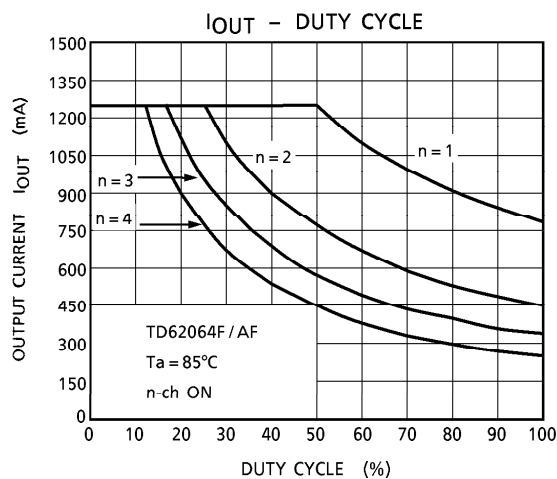
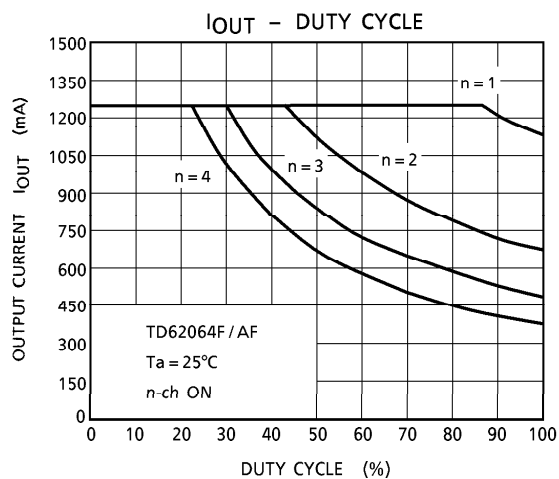
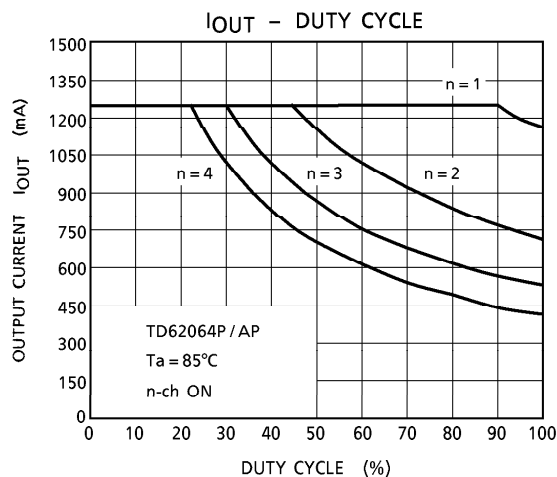
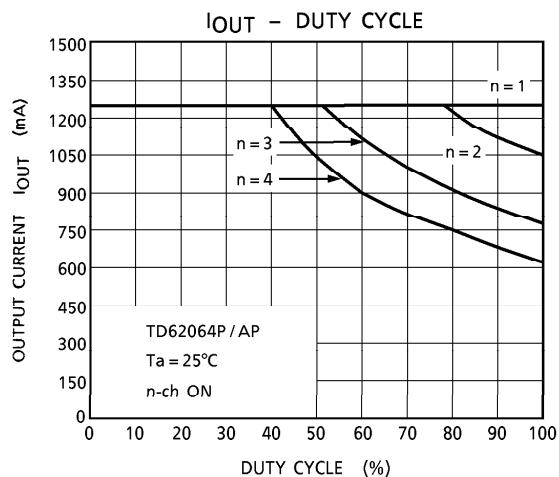


7. t_{ON} , t_{OFF}



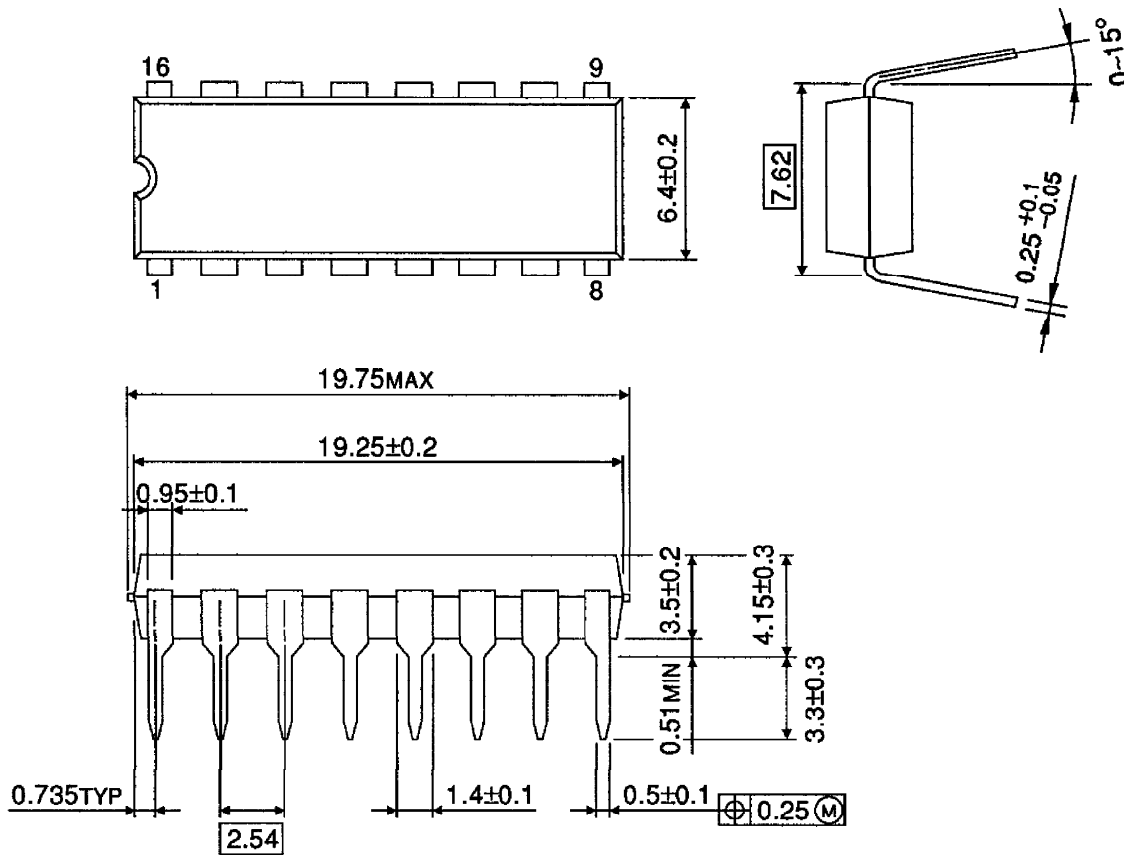
- (Note 1) Pulse Width $50\mu\text{s}$, Duty Cycle 10%
Output Impedance 50Ω , $t_r \leq 5\text{ns}$, $t_f \leq 10\text{ns}$
(Note 2) C_L includes probe and jig capacitance





OUTLINE DRAWING
 DIP16-P-300A

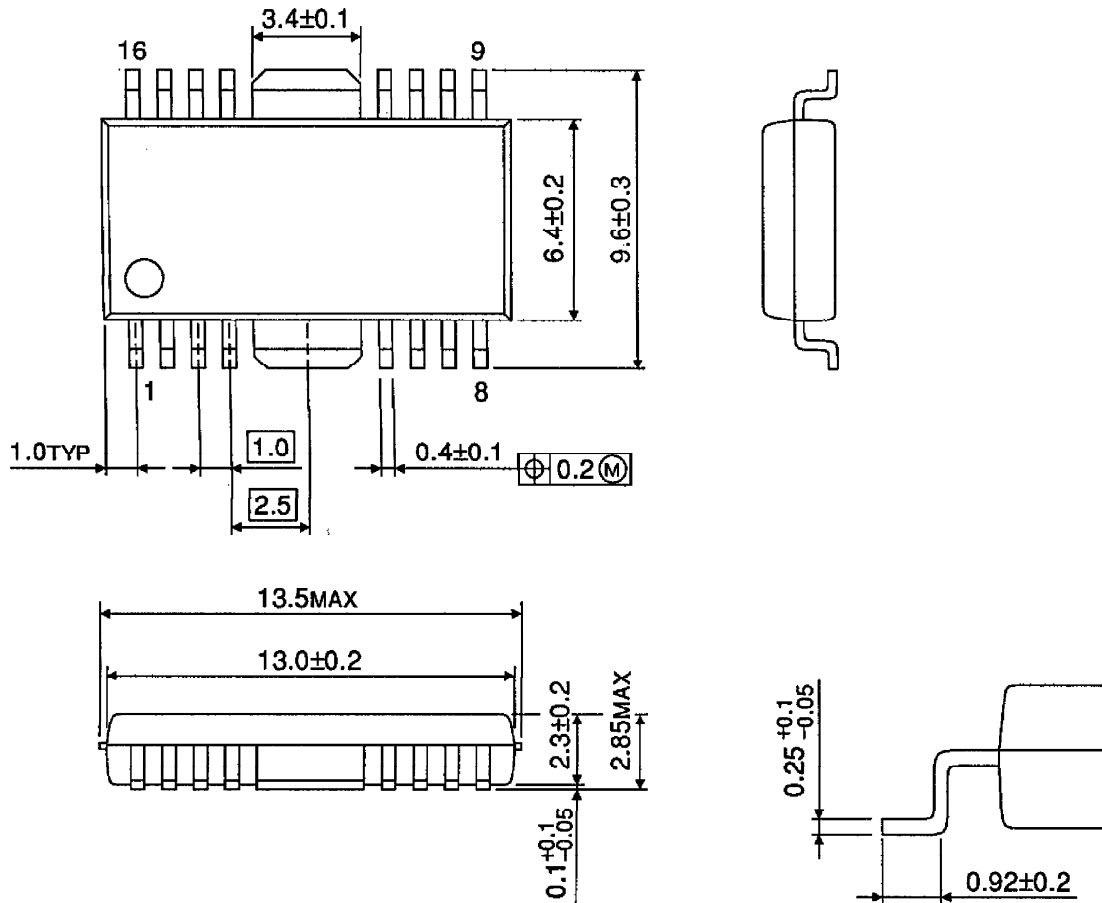
Unit : mm



Weight : 1.11g (Typ.)

OUTLINE DRAWING
 HSOP16-P-300

Unit : mm



Weight : 0.50g (Typ.)